

MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{DSS}	Drain to Source Voltage	60	V	
V _{GS}	Gate to Source Voltage	±20	V	
	Drain Current Continuous (V _{GS} = 10V)	1.7	•	
D	Pulsed	10	— A	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	74	mJ	
P _D	Power Dissipation	1.1	W	
T _J , T _{STG}	Operating and Storage Temperature	-55 to +150	°C	
$R_{\theta JC}$	Thermal Resistance Junction to Case	75	°C/W	
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-252, 1in ² copper pad area	111	°C/W	

Note:

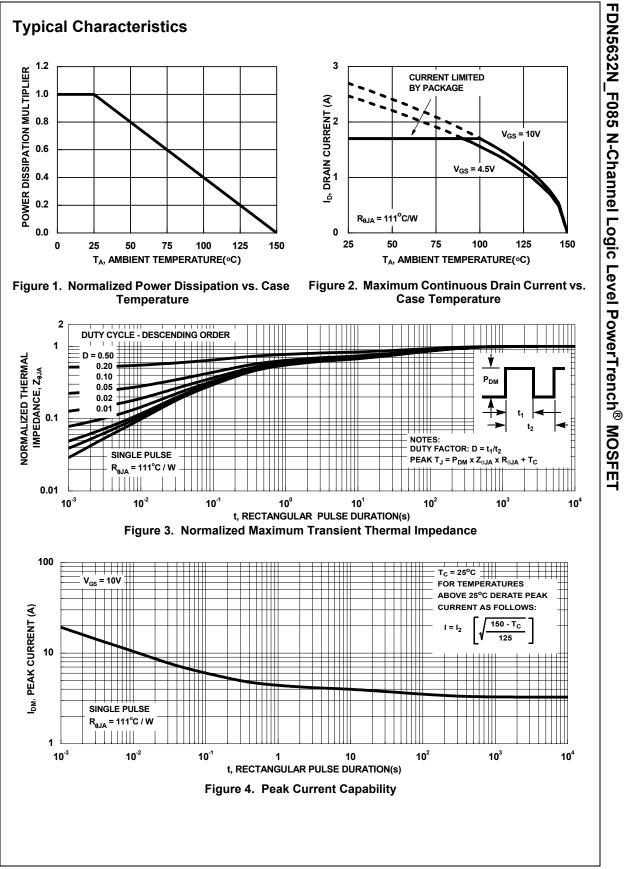
1: E_{AS} of 74mJ is 100% test at L=80mH, I_{AS} =1.4A, starting T_{J} = 25 $^{\circ}C$

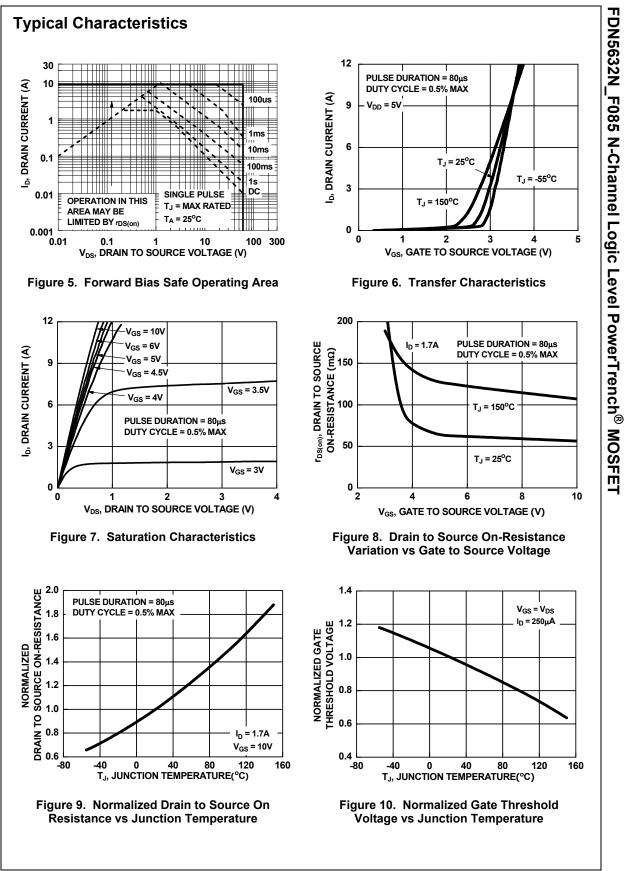
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
5632	FDN5632N_F085	SSOT3	7"	8mm	3000 units
			1		<u> </u>
15 Fairchild Semicon	ductor Corporation		1		www.fairchildsemi.c

	Parameter	Test Conditions	Min	Тур	Max	Units	
off Cha	racteristics						
BVDSS	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	60	-	-	V	
1033		$V_{\rm DS} = 48V,$	-	-	1	-	
DSS	Zero Gate Voltage Drain Current	$V_{GS} = 0V \qquad T_A = 125^{\circ}C$	-	-	250	μA	
GSS	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA	
)n Cha	racteristics						
/ _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	1	2.0	3	V	
GS(th)		$I_{\rm D} = 1.7$ A, $V_{\rm GS} = 10$ V	-	57	82		
		$I_D = 1.6A, V_{GS} = 6V$	-	62	88	-	
DS(on)	Drain to Source On Resistance	$I_D = 1.6A, V_{GS} = 4.5V$		70	98	mΩ	
DS(on)		$I_{\rm D} = 1.7$ A, $V_{\rm GS} = 10$ V,		10	50	11152	
		$T_A = 150^{\circ}C$	-	107	135		
ynami	c Characteristics						
Siss	Input Capacitance		-	475	-	pF	
2 _{0SS}	Output Capacitance	$V_{\rm DS}$ = 15V, $V_{\rm GS}$ = 0V,	-	60	-	pF	
- Crss	Reverse Transfer Capacitance	f = 1MHz	-	30	_	pF	
				1.4		Ω	
	Gate Resistance	f = 1MHz					
₹ _G	Gate Resistance	f = 1MHz	-		- 12		
₹ _G ⊋ _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V $V_{DD} = 20V$	-	9.2	12	nC	
G g(TOT) gs gd		$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$			- - -		
R _G A _{g(TOT)} A _{gs} A _{gd} E lectr i	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge cal Characteristics T _A = 2	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$	-	9.2 1.5	-	nC nC	
R _G Δ _{g(TOT)} Δ _{gs} Δ _{gd} Electri Symbol	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge cal Characteristics T _A = 2	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted	-	9.2 1.5 1.4	-	nC nC nC	
R _G 2 _{g(TOT)} 2 _{gs} 2 _{gd} Electri Symbol Switch	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics T _A = 2 Parameter	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted	-	9.2 1.5 1.4	-	nC nC nC	
R _G Q _{g(TOT)} Q _{gs} Q _{ga} Electri Symbol Switch	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics T _A = 2 Parameter hing Characteristics	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$	- - - Min	9.2 1.5 1.4 Typ	- - Max	nC nC nC	
R _G Q _{g(TOT)} Q _{gs} Q _{gd} Electri Symbol Switch	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics TA = 2 Parameter hing Characteristics Turn-On Time	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$ $V_{DD} = 30V, I_D = 1.0A$	- - - Min	9.2 1.5 1.4 Typ	- - Max	nC nC nC Unit:	
R _G Q _{g(TOT)} Q _{gs} Q _{gd} Electri Symbol Switch on d(on) r	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics TA = 2 Parameter hing Characteristics Turn-On Time Turn-On Delay Time	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$	- - - Min	9.2 1.5 1.4 Typ - 15 1.7	- - Max 30 -	nC nC nC Units	
3 G 2g(TOT) 2 2gg 3 2gg 3 Symbol 3 Switch 3 on 4(on) r 4(off)	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics T _A = 2: Parameter ning Characteristics Turn-On Time Turn-On Delay Time Rise Time	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$ $V_{DD} = 30V, I_D = 1.0A$	- - - - - - -	9.2 1.5 1.4 Typ	- - - - - - - -	nC nC nC Units	
R_G $Q_{g(TOT)}$ Q_{gs} Q_{gd} Electri Symbol Switcl on d(on) r d(off) f	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics Tarameter ning Characteristics Turn-On Time Turn-On Delay Time Rise Time Turn-Off Delay Time	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$ $V_{DD} = 30V, I_D = 1.0A$	- - - - - - - - -	9.2 1.5 1.4 Typ - 15 1.7 5.2	- - Max 30 - - -	nC nC nC Units ns ns ns ns	
R _G Q _{g(TOT)} Q _{gs} Q _{gd} Electri Symbol Switch on d(on) r d(off) f off	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics TA = 2: Parameter hing Characteristics Turn-On Time Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$ $V_{DD} = 30V, I_D = 1.0A$	- - - - - - - - -	9.2 1.5 1.4 Typ - 15 1.7 5.2	- - Max 30 - - - -	nC nC nC Units ns ns ns ns ns ns	
R _G 2 _{g(TOT)} 2 _{gs} 2 _{gd} Electri Symbol Switch on d(on) r d(off) f off Drain-S	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics T _A = 2 Parameter ning Characteristics Turn-On Time Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Time ource Diode Characteristics	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted Test Conditions $V_{DD} = 30V, I_D = 1.0A$ $V_{GS} = 10V, R_{GEN} = 6\Omega$	- - - - - - - - -	9.2 1.5 1.4 Typ - 15 1.7 5.2 1.3 -	- - Max 30 - - - - 12.9	nC nC nC Unit: ns ns ns ns ns	
R _G Q _{g(TOT)} Q _{gs} Q _{gd} Electri Symbol Switch on d(on) r d(off) f off	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics T _A = 2 Parameter ning Characteristics Turn-On Time Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Time	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$ $V_{DD} = 30V, I_D = 1.0A$ $V_{GS} = 10V, R_{GEN} = 6\Omega$ $I_{SD} = 1.7A$	- - - - - - - - - - -	9.2 1.5 1.4 Typ - 15 1.7 5.2 1.3 - 0.8	- - - - - - - - - - - - - - - - 12.9	nC nC nC Unit ns ns ns ns ns	
R_G $Q_{g(TOT)}$ Q_{gs} Q_{gd} Electri Symbol Switch Switch on d(on) r d(off) f off Drain-S / _{SD}	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics T _A = 2 Parameter hing Characteristics Turn-On Time Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Time Source Diode Characteristics	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test \text{ Conditions}$ $V_{DD} = 30V, I_D = 1.0A$ $V_{GS} = 10V, R_{GEN} = 6\Omega$ $I_{SD} = 1.7A$ $I_{SD} = 0.85A$	- - - - - - - - - - - - - - - -	9.2 1.5 1.4 Typ - 15 1.7 5.2 1.3 - 0.8 0.8	- - - - - - - - - - - - - - - - - - -	nC nC nC Units ns ns ns ns ns v	
R _G 2 _{g(TOT)} 2 _{gs} 2 _{gd} Electri Symbol Switch on d(on) r d(off) f off Drain-S	Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge ical Characteristics T _A = 2 Parameter ning Characteristics Turn-On Time Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-Off Time ource Diode Characteristics	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$ $I_D = 1.7A$ 5°C unless otherwise noted $Test Conditions$ $V_{DD} = 30V, I_D = 1.0A$ $V_{GS} = 10V, R_{GEN} = 6\Omega$ $I_{SD} = 1.7A$	- - - - - - - - - - -	9.2 1.5 1.4 Typ - 15 1.7 5.2 1.3 - 0.8	- - - - - - - - - - - - - - - - 12.9	nC nC nC Units ns ns ns ns ns	

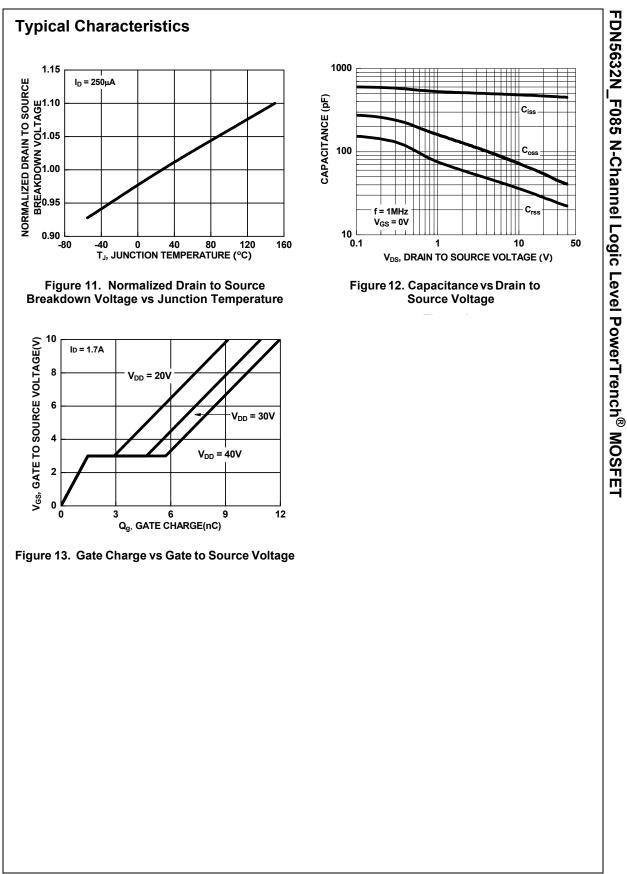
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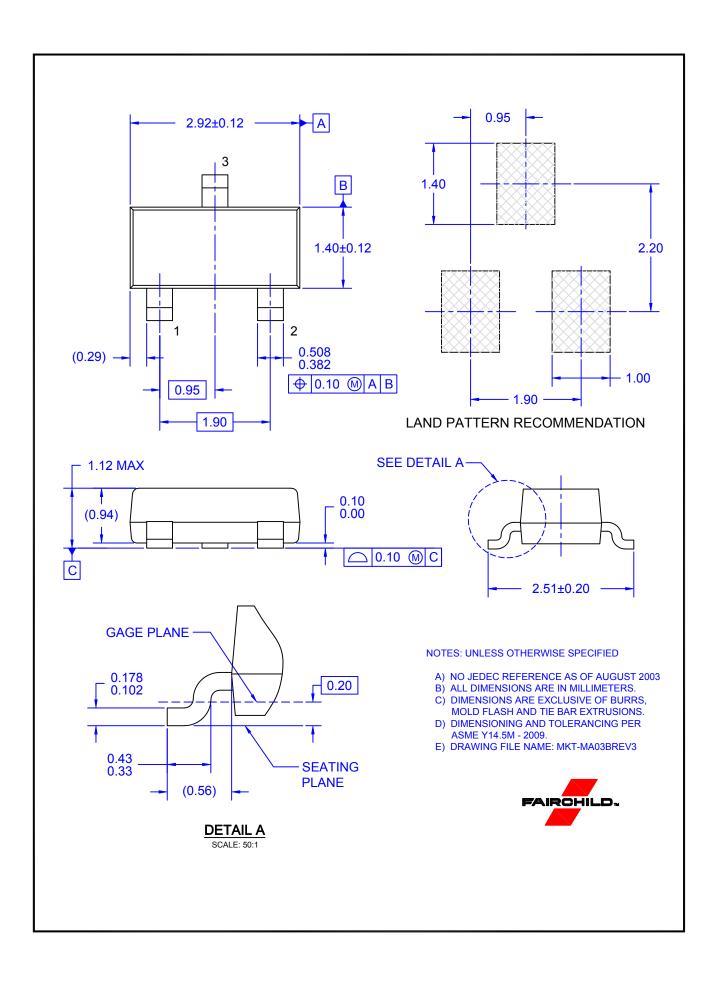




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